

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L10	1319493	channel	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/16 12:33
L11	3359723	body	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/16 12:33
L12	9264	SiGe	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/16 12:33
L13	23149	silicon adj germanium	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/16 12:33
L14	343	"Si.sub.xGe.sub.1-x"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/16 12:34
L15	730033	transistor\$1	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/16 12:34
L16	93590	M?SFET\$1	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/16 12:36
L17	118203	FET\$1	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/16 12:35
L18	4015	NFET\$1	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/16 12:36
L19	3909	PFET\$1	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/16 12:35

L20	3008	NM?SFET\$1	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/16 12:36
L21	2709	PM?SFET\$1	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/16 12:36
L22	73947	relaxed	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/16 12:36
L23	21554	strained	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/16 12:36
L24	913777	silicon	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/16 12:37
L25	1423708	Si	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/16 12:37
L26	209	(15 or 16 or 17 or 18 or 19 or 20 or 21) and ((channel or body) same (22 near2 (12 or 13 or 14))) and (22 near2 (24 or 25))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/16 12:50
L27	14261	high adj2 mobility	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/16 12:50
L28	873	enhanced adj2 mobility	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/16 12:50
L29	126	26 and (27 or 28)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/16 12:50

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S86	4815	ultra adj high adj vacuum	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/16 18:32
S87	105608	chemical adj vapor adj deposit\$3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/16 18:32
S88	137329	cvd	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/16 18:32
S89	23149	silicon adj germanium	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/16 18:33
S90	343	"Si.sub.xGe.sub.1-x"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/16 18:33
S91	9264	SiGe	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/16 18:33
S92	913777	silicon	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/16 18:33
S93	1423708	Si	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/16 18:33
S94	195	((S86 adj (S87 or S88)) same (S89 or S90 or S91)) and ((S86 adj (S87 or S88)) same (S92 or S93))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/16 18:36
S95	6653	germane	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/16 18:36

S96	6810	dichlorosilane	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/16 18:36
S97	8	((S86 adj (S87 or S88)) same (S89 or S90 or S91) same (S95 or S96)) and ((S86 adj (S87 or S88)) same (S92 or S93))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/16 18:38
S98	2	((S86 adj (S87 or S88)) same (S89 or S90 or S91) same S95 same S96) and ((S86 adj (S87 or S88)) same (S92 or S93))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/16 18:39
S99	2	((S86 adj (S87 or S88)) same (S89 or S90 or S91) same S95 same S96)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/16 18:41
S100	3	((S86 adj (S87 or S88)) same S95 same S96)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/16 18:41